

# **CFCCARBON CO., LTD**

## C/C vs C/SiC properties

Product name: C/C; C/SiC C/C type: weave/sewn; C/SiC type: C/C+CVD/PIP

Main application: anti-ablation, thrust chamber, throat lining;

Structural materials

# Comparision of C/C&C/SiC properties

No.	Characteristics	Items	C/C	C/SiC	Unit
1	Low density	density	1.8~1.9	1.9~2.0	g/cm <sup>3</sup>
2	lliab otropath	3points bending strength	170~200	500~700	MPa
3	High strength	Elastic modulus	55~65	70~85	GPa
4		Fracture toughness	65~80	26~32	MPa.m <sup>1/2</sup>
5		C.T.E	<2.5	<2.5	10 <sup>-6</sup> .K <sup>-1</sup>
6		Thermal conductivity	>3	>3	W/(m.k)
7	High temperature	Specific heat	>0.6	>0.6	J/(g.k)
8 stab	stability	thermal diffusion (RT-1200°C)	<2.8	<2.8	mm <sup>-2</sup> /s
9	anti-ablation; high	anti ablatian manartu	7X10 <sup>-3</sup>	5X10 <sup>-3</sup>	g/s
10	temp resistance	anti-ablation property	13X10 <sup>-3</sup>	10X10 <sup>-3</sup>	mm/s

## Ablation properties of C/SiC composites under different conditions

Items	Туре	Density (g/cm3)	Open porosity (%)	Ablation temperature (°C)	Ablation time	Linear ablation rate ( mm/s)	Weight ablation rate (mg/s)
1	PIP	1.90	≤10	2300	60	0.068	2.48
2	PIP	1.95	≤8	2300	60	0.066	3.23
3	LSI	2.10	≤5	2300	60	0.023	1.68
4	LSI	2.30	≤1	2300	60	0.012	0.34

#### Conclusion:

- 1. The test was done at temperature 2300 ℃.
- 2. At temperature 2300 ℃ or higher, the LSI type C/SiC is better than PIP type C/SiC.
- 3. At temperature 2300  $^{\circ}$ C or higher, the SiC will peels /falls off from the body C/SiC, Randomly /Unevenly.



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### C/SiC: Temperature resistance under different temperatures

	air /oxygen °ℂ	≤400	No oxidation
		400-800	micro oxidation
		800-1600	slightly oxidized
		1600-3000	speed up the oxidation
Temp resistance	Inert gases ℃	2700	SiC start to gasify
remp resistance		≤3200	carbon fiber still stable
	vacuum °C	2700	SiC start to gasify, more
			faster than in the inert air
		≤3200	carbon fiber still stable

#### Conclusion:

- 1. C/SiC material is stable at 1600-1800  $^{\circ}$ C, or under 1600  $^{\circ}$ C.
- 2. At 2600-2700  $^{\circ}$ C or above, the SiC in the C/SiC is severely exfoliated and non-uniform!

Note: The above technical parameters are for reference only, and the performance indicators of different carbon fiber models and combined processes are different, which can be adjusted according to actual needs

Max size: W800-H1000-T50mm, or D800/700-H1000mm, other sizes to confirm!

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